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### Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







## **EFC4627R**



## ON Semiconduct

# N-Channel Power MOSFET 12V, 6A, 29.5mΩ, Dual EFCP

#### **Features**

- 2.5V drive
- Protection diode in

- Common-drain type
- Halogen free compliance

#### **Applications**

• Lithium-ion battery charging and discharging switch

#### **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>		12	V
Gate to Source Voltage	V <sub>GSS</sub>		±10	V
Source Current (DC)	IS		6	Α
Source Current (Pulse)	I <sub>SP</sub>	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm <sup>2</sup> ×0.8mm)	1.4	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **Thermal Resistance Ratings**

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	84	°C /W
When mounted on ceramic substrate (5000mm <sup>2</sup> ×0.8mm)			

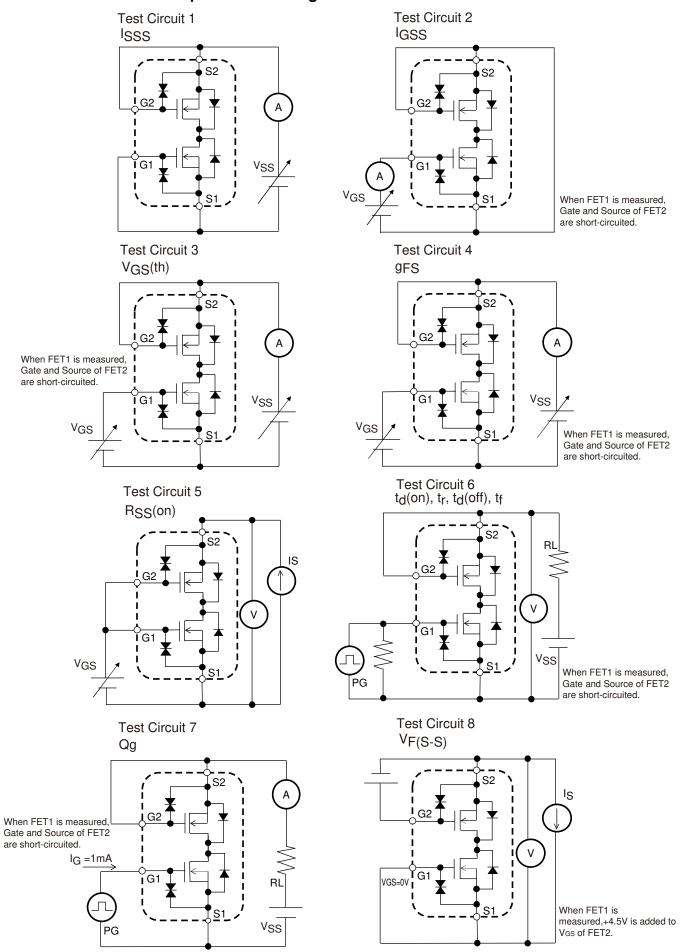
#### **Electrical Characteristics** at Ta = 25°C

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Parameter	Symbol Conditions		min	typ	max	Unit	
Source to Source Breakdown Voltage	V(BR)SSS	I <sub>S</sub> =1mA, V <sub>GS</sub> =0V	Test Circuit 1	12			٧
Zero-Gate Voltage Source Current	ISSS	V <sub>SS</sub> =10V, V <sub>GS</sub> =0V	Test Circuit 1			1	μΑ
Gate to Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>SS</sub> =0V	Test Circuit 2			±1	μΑ
Gate Threshold Voltage	V <sub>GS</sub> (th)	V <sub>SS</sub> =6V, I <sub>S</sub> =1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	gFS	V <sub>SS</sub> =6V, I <sub>S</sub> =2A	Test Circuit 4		4.8		S
Static Source to Source On-State Resistance	Rss(on)1	I <sub>S</sub> =2A, V <sub>GS</sub> =4.5V	Test Circuit 5	18.5	23.9	29.5	mΩ
	R <sub>SS</sub> (on)2	I <sub>S</sub> =2A, V <sub>GS</sub> =4.0V	Test Circuit 5	19.7	25.4	31.3	mΩ
	Rss(on)3	I <sub>S</sub> =2A, V <sub>GS</sub> =3.8V	Test Circuit 5	20.3	26.1	32.3	mΩ
	Rss(on)4	I <sub>S</sub> =2A, V <sub>GS</sub> =3.1V	Test Circuit 5	23.5	30.3	39.0	mΩ
	Rss(on)5	I <sub>S</sub> =2A, V <sub>GS</sub> =2.5V	Test Circuit 5	29.3	37.7	50.5	mΩ
Turn-ON Delay Time	t <sub>d</sub> (on)				75		ns
Rise Time	t <sub>r</sub>	V <sub>SS</sub> =6V, V <sub>GS</sub> =4.5V, I <sub>S</sub> =2A	Test Circuit 6		740		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)				2340		ns
Fall Time	tf				2320		ns
Total Gate Charge	Qg	V <sub>SS</sub> =6V, V <sub>GS</sub> =4.5V, I <sub>S</sub> =6A	Test Circuit 7		13.4		nC
Forward Source to Source Voltage	V <sub>F</sub> (S-S)	Is=3A, Vgs=0V	Test Circuit 8		0.76		V

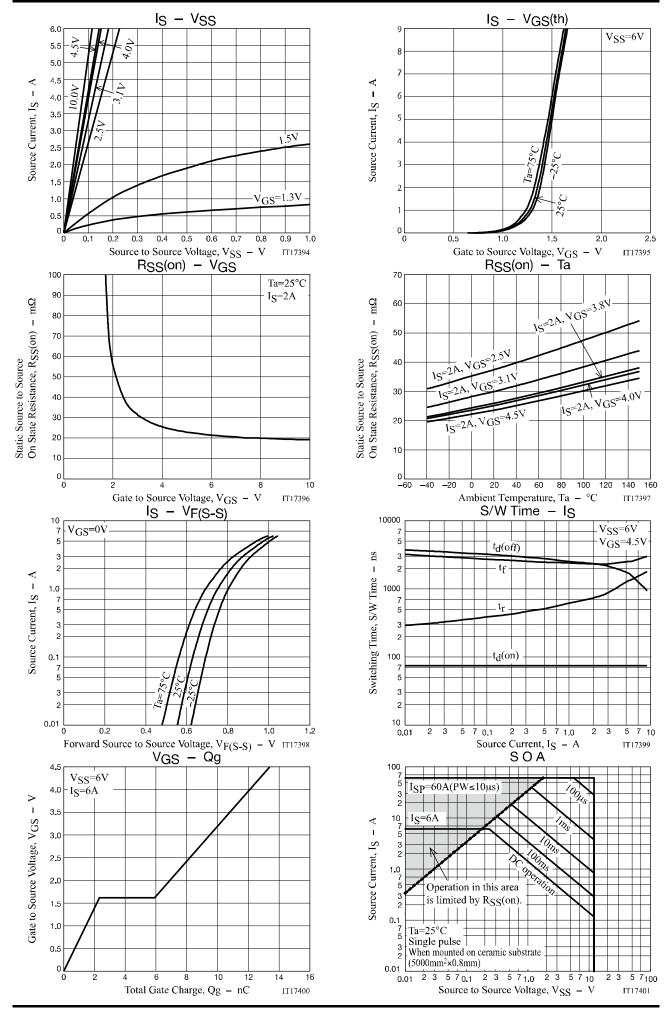
#### **ORDERING INFORMATION**

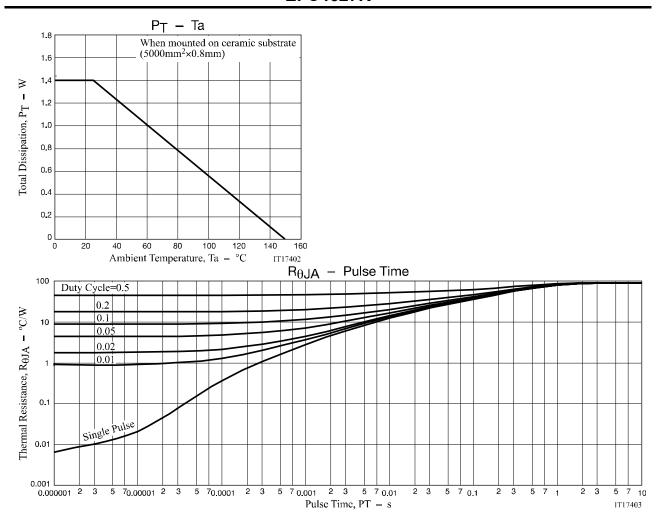
See detailed ordering and shipping information on page 5 of this data sheet.

#### Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.





#### **Package Dimensions**

EFC4627R-TR

#### EFCP1010-4DG-020

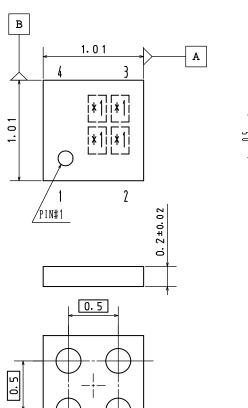
Unit: mm

1: Source1

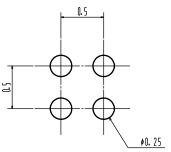
2: Gate1

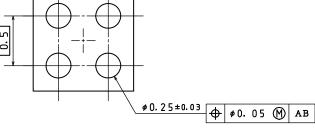
3: Gate2

4: Source2



## Recommended Soldering Footprint

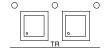




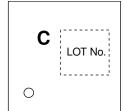
#### **Ordering & Package Information**

Device	Package	Shipping	note
EFC4627R-TR	EFCP	8,000 pcs. / reel	Pb-Free and Halogen Free

#### Packing Type: TR

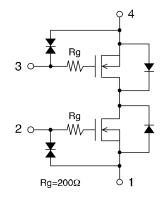


#### Marking



#### **Electrical Connection**

\*1:Lot indication



Note on usage: Since the EFC4627R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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